

## APM4115PUC-TRL-VB Datasheet P-Channel 40 V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	-40					
$R_{DS(on)}(\Omega)$ at $V_{GS}$ = -10 V	0.012					
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS}$ = -4.5 V	0.015					
I <sub>D</sub> (A)	-50					
Configuration	Single					

#### FEATURES

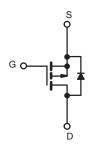
- Trench power MOSFET
- Package with low thermal resistance
- 100 % R<sub>g</sub> and UIS tested



FREE

# TO-252

Top View



P-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_C = 25$ °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V <sub>DS</sub>	-40	v			
Gate-Source Voltage	V <sub>GS</sub>	± 20	v			
Continuous Drain Current	T <sub>C</sub> = 25 °C <sup>a</sup>	1	-50			
Continuous Drain Current	T <sub>C</sub> = 125 °C	۱ <sub>D</sub>	-39			
Continuous Source Current (Diode Conduction) <sup>a</sup>	I <sub>S</sub>	-50	A			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	-200			
Single Pulse Avalanche Current		I <sub>AS</sub>	-40			
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	80	mJ		
	T <sub>A</sub> = 25 °C		3			
Maximum Power Dissipation <sup>b</sup>	T <sub>C</sub> = 25 °C	PD	136	W		
	T <sub>C</sub> = 125 °C		45	1		
Operating Junction and Storage Temperature Rar	T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C			

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount <sup>c</sup>	R <sub>thJA</sub>	50	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	1.1	0/10

#### Notes

a. Package limited.

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

				5	3°v1	Bsem	
				wv			
	··						
SYMBOL	1	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
V <sub>DS</sub>	V <sub>GS</sub> =	= 0 V, I <sub>D</sub> = -250 μA	-40	-	-	V	
V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{GS}$ , $I_D$ = -250 $\mu$ A	-1.0	-	-3.5	v	
I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -40 V	-	-	-1		
	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μA	
	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	-150		
I <sub>D(on)</sub>	$V_{GS} = -10 V$	$V_{DS} \le -5 V$	-50	-	-	А	
R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -17 A	-	0.012	-		
	$V_{GS} = -10 \text{ V}$	I <sub>D</sub> = -10 A, T <sub>J</sub> = 125 °C	-	0.017	-	Ω	
	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -10 A, T <sub>J</sub> = 175 °C	-	0.020	-		
	V <sub>GS</sub> = -4.5 V	I <sub>D</sub> = -14 A	-	0.015	-	1	
<b>g</b> <sub>fs</sub>	V <sub>DS</sub> =	-15 V, I <sub>D</sub> = -17 A	-	61	-	S	
				•	-		
C <sub>iss</sub>			-	3000	-		
	SYMBOL V <sub>DS</sub> V <sub>GS(th)</sub> I <sub>GSS</sub> I <sub>DSS</sub> I <sub>D(on)</sub> R <sub>DS(on)</sub> gfs	$\begin{tabular}{ c c c c c c } \hline V_{DS} & V_{GS} & V_{GS} & = \\ \hline V_{GS}(th) & V_{DS} & = \\ \hline I_{GSS} & V_{DS} & = \\ \hline I_{DSS} & V_{GS} & = 0 \ V & V_{GS} & = -10 \ V & V_{GS} & = -10$	$\begin{tabular}{ c c c c c } \hline SYMBOL & TEST CONDITIONS \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = -250 \ \mu A \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline I_{DSS} & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C \\ \hline I_{D(on)} & V_{GS} = -10 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -17 \ A \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -45 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -45 \ V & I_D = -17 \ A \\ \hline \end{tabular}$	$\begin{array}{ c c c c c c } SYMBOL & TEST CONDITIONS & MIN. \\ \hline \\ & V_{DS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A & -40 \\ \hline \\ V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = -250 \ \mu A & -1.0 \\ \hline \\ & I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & I_{D(on)} & V_{GS} = -10 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -17 \ A & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 125 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -15 \ V, \ I_D = -17 \ A & - \\ \hline \end{array}$	$\begin{tabular}{ c c c c c c c } \hline SYMBOL & TEST CONDITIONS & MIN. & TYP. \\ \hline SYMBOL & V_{GS} = 0 V, I_D = -250 \ \mu A & -40 & - \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = -250 \ \mu A & -1.0 & - \\ \hline V_{GS} & V_{DS} = 0 V, V_{GS} = \pm 20 \ V & - & - \\ \hline I_{GSS} & V_{DS} = 0 V, V_{GS} = \pm 20 \ V & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 125 \ ^{\circ}C & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 125 \ ^{\circ}C & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 175 \ ^{\circ}C & - & - \\ \hline I_{D(on)} & V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.012 \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.020 \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.020 \\ \hline V_{GS} = -40 \ V, I_D = -17 \ A & - & 0.015 \\ \hline g_{fs} & V_{DS} = -45 \ V, I_D = -17 \ A & - & 61 \\ \hline \end{tabular}$	www.VBsc           symbol         TEST CONDITIONS         MIN.         TYP.         MAX. $V_{DS}$ $V_{GS} = 0 V$ , $I_D = -250 \mu A$ $-40$ $  V_{GS(th)}$ $V_{DS} = V_{GS}$ , $I_D = -250 \mu A$ $-10$ $ -3.5$ $I_{GSS}$ $V_{DS} = 0 V$ , $V_{GS} = \pm 20 V$ $  \pm 100$ $I_{GSS}$ $V_{DS} = 0 V$ $V_{DS} = -40 V$ $  -1$ $I_{DSS}$ $V_{GS} = 0 V$ $V_{DS} = -40 V$ $  -100$ $I_{DSS}$ $V_{GS} = 0 V$ $V_{DS} = -40 V$ , $T_J = 125 °C$ $  -150$ $I_{D(on)}$ $V_{GS} = -10 V$ $V_{DS} \le -5 V$ $-50$ $  R_{DS(on)}$ $V_{GS} = -10 V$ $I_D = -17 A$ $ 0.012$ $ V_{GS} = -10 V$ $I_D = -10 A, T_J = 125 °C$ $ 0.012$ $ V_{GS} = -10 V$ $I_D = -10 A, T_J = 175 °C$ $ 0.020$ $  g_{fs}$ <	

Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			-	3000	-	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -25 V, f = 1 MHz	-	508	635	pF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	352	440	
Total Gate Charge <sup>c</sup>	Qg		V <sub>DS</sub> = -30 V, I <sub>D</sub> = -50 A	-	60	80	nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = -10 \text{ V}$		-	5.7	8.6	
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	14.7	22	
Gate Resistance	R <sub>g</sub>	f = 1 MHz		1.5	3	4.5	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	10	15	
Rise Time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub> =	$V_{DD} = -20 \text{ V}, \text{ R}_{\text{I}} = 0.4 \Omega$		12	18	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong -50 \text{ A},  V_{\text{GEN}} = -10  \text{V},  \text{R}_{\text{g}} = 1  \Omega$		-	40	60	ns
Fall Time <sup>c</sup>	t <sub>f</sub>			-	16	24	
Source-Drain Diode Ratings and Characteristics <sup>b</sup>							
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	-200	А
Forward Voltage	V <sub>SD</sub>	$I_F = -50 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		-	-1	-1.5	V

#### Notes

a. Pulse test; pulse width  $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$ 

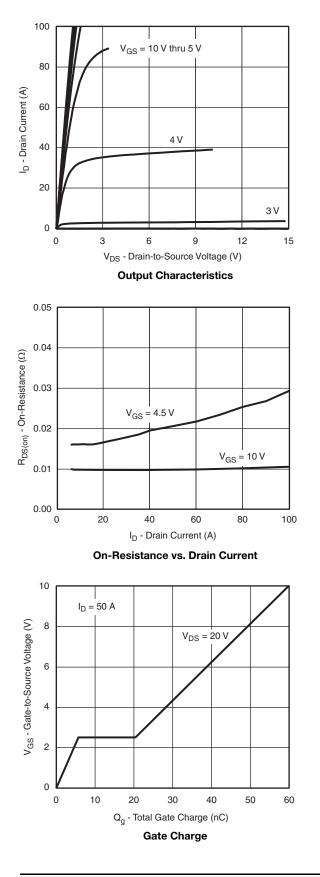
b. Guaranteed by design, not subject to production testing.

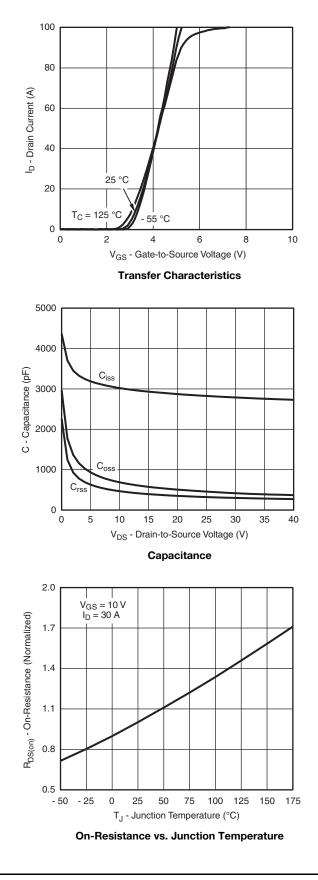
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



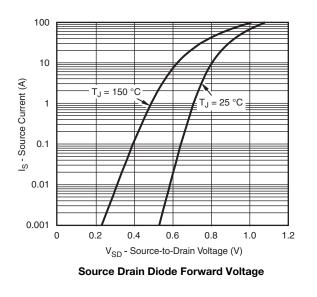
#### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

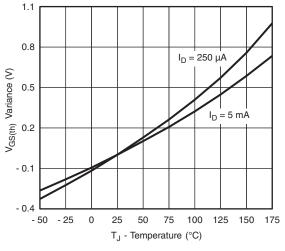




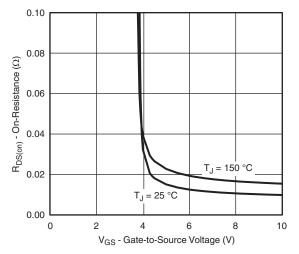


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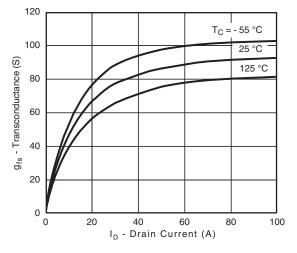




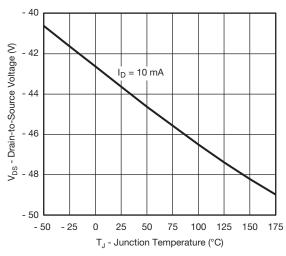


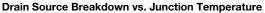


**On-Resistance vs. Gate-to Source Voltage** 



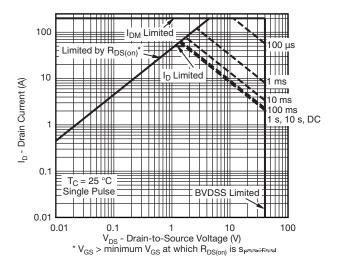




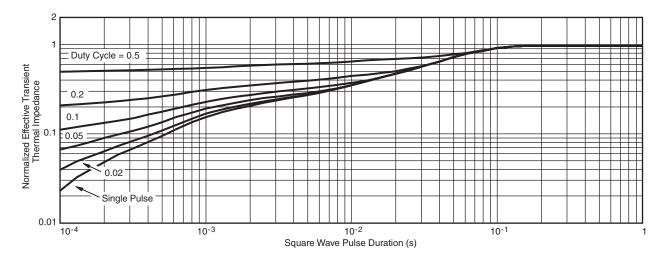




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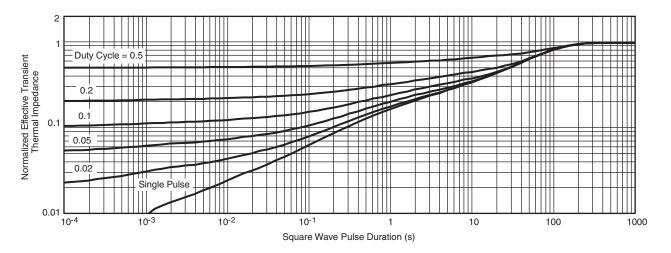


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case





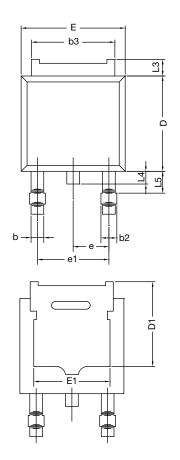
#### Normalized Thermal Transient Impedance, Junction-to-Ambient

#### Note

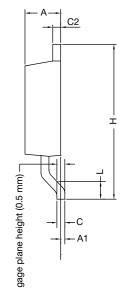
- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.





### **TO-252AA Case Outline**



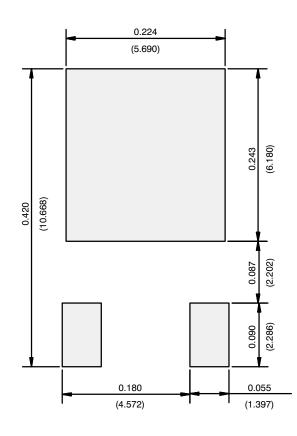
	MILLIN	IETERS	INC	HES		
DIM.	MIN.	MAX.	MIN.	MAX.		
А	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	4.10	-	0.161	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	e 2.28 BSC 0.090 BSC					
e1	4.56	4.56 BSC		BSC		
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	-	1.02	-	0.040		
L5	1.01	1.52	0.040	0.060		
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019						

Note

• Dimension L3 is for reference only.



#### **RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)**



Recommended Minimum Pads Dimensions in Inches/(mm)



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